

3 Northway Lane North Latham, New York 12110.

Tollfree:1.800.984.5337 Phone:1.518.956.2980 Fax:1.518.785.4725

Http://www.marktechopto.com

SPECIFICATION

PART NO.: MT5470E-OR

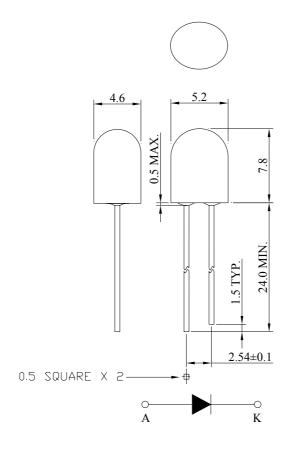
5.2×4.6mm OVAL LED LAMP





Description

This amber lamp is made with AlGaInP/GaAs chip and white diffused epoxy resin.



Notes:

- 1. All dimensions are in mm.
- 2. Tolerance is±0.25mm unless otherwise noted.

Description

	LED Chip		
Part No.	Material	Emitting Color	Lens Color
MT 5470E-OR	AlGaInP/GaAs	Amber	White diffused

VER.: 01 Date: 2013/02/27 Page: 1/5



Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Rating	Unit
Power Dissipation	PD	125	mW
Reverse Voltage	VR	5	V
D.C. Forward Current	If	50	mA
Reverse (Leakage) Current	Ir	100	μА
Peak Current(1/10Duty Cycle,0.1ms Pulse Width.)	If(Peak)	200	mA
Operating Temperature Range	Topr.	-40 to +95	°C
Storage Temperature Range	Tstg.	-40 to +100	°C
Soldering Temperature(1.6mm from body)	Tsol.	Dip Soldering : 260°C for 5 Hand Soldering : 350°C for 3	

Electrical and Optical Characteristics:

Parai	meter	Symbol	Condition	Min.	Тур.	Max.	Unit
Luminous Intens	ity	Iv	If=20mA	2130	3000		mcd
Forward Voltage		Vf	If=20mA		2.1	2.6	V
Peak Wavelength	1	λр	If=20mA		610		nm
Dominant Wavel	ength	λd	If=20mA	600	605	609	nm
Reverse (Leakag	e) Current	Ir	Vr=5V			100	μΑ
ViewingAngle	VERTICAL	2θ 1/2	If=20mA		40		deg
	HORIZONTAL	2θ 1/2	If=20mA		60		
Spectrum Line H	lalfwidth	Δλ	If=20mA		17		nm

Notes: 1. The datas tested by IS tester.

2. Customer's special requirements are also welcome.

VER.: 01 Date: 2013/02/27 Page: 2/5



Specifications for Bin Grading:

Iv(mcd)			
BIN	MIN.	MAX.	
V	2130	3000	
W	3000	4180	
X	4180	5860	

Specifications for Vf Group:

Vf(V)			
Group	MIN.	MAX.	
V1	1.6	1.8	
V2	1.8	2.0	
V3	2.0	2.2	
V4	2.2	2.4	
V5	2.4	2.6	

^{*}Majority VF bins are highlighted in Yellow.

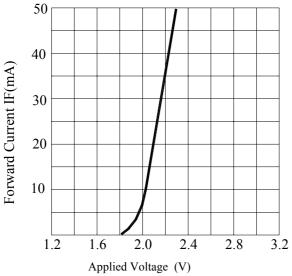
Specifications for Wavelength Group:

λ d(nm)		
Group	MIN.	MAX.
X2	600	603
Х3	603	606
X4	606	609

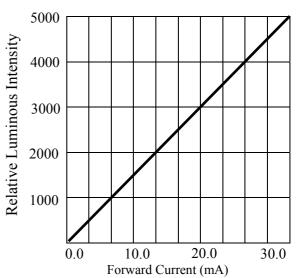
VER.: 01 Date: 2013/02/27 Page: 3/5



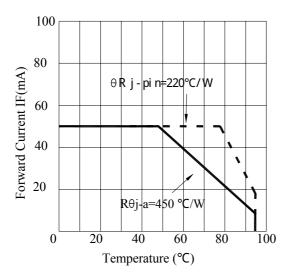
Typical Electrical / Optical Characteristics Curves:



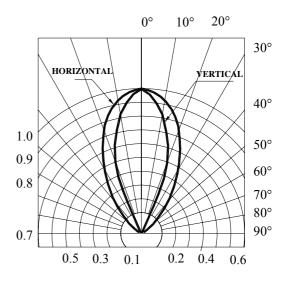
FORWARD CURRENT VS.APPLIED VOLTAGE



FORWARD CURRENT VS. LUMINOUS INTENSITY



FORWARD CURRENT VS. AMBIENT TEMPERATURE



RADIATION DIAGRAM

VER.: 01 Date: 2013/02/27 Page:4/5

MT5470E-OR

5.2×4.6mm OVAL LED LAMP

Precautions:

TAKE NOTE OF THE FOLLOWING IN USE OF LED

1. Temperature in use

Since the light generated inside the LED needs to be emitted to outside efficiently, a resin with high light transparency is used; therefore, additives to improve the heat resistance or moisture resistance (silica gel, etc) which are used for semiconductor products such as transistors cannot be added to the resin.

Consequently, the heat resistant ability of the resin used for LED is usually low; therefore, please be careful on the following during use.

Avoid applying external force, stress, and excessive vibration to the resins and terminals at high temperature. The glass transition temperature of epoxy resin used for the LED is approximately 120-130°C.

At a temperature exceeding this limit, the coefficient of liner expansion of the resin doubles or more compared to that at normal temperature and the resin is softened.

If external force or stress is applied at that time, it may cause a wire rupture.

2. Soldering

Please be careful on the following at soldering.

After soldering, avoided applying external force, stress, and excessive vibration until the products go to cooling process (normal temperature), <Same for products with terminal leads>

(1) Soldering measurements:

Distance between melted solder side to bottom of resin shall be 1.6mm or longer.

(2) Dip soldering:

Pre-heat: 90°C max. (Backside of PCB), Within 60 seconds.

Solder bath: 260±5°C (Solder temperature), Within 5 seconds.

(3) Hand soldering: 350°C max. (Temperature of soldering iron tip), Within 3 seconds.

3. Insertion

Pitch of the LED leads and pitch of mounting holes need to be same.

Others

Since the heat resistant ability of the LED resin is low, SMD components are used on the same PCB, please mount the LED after adhesive baking process for SMD components. In case adhesive baking is done after LED lamp insertion due to a production process reason, make sure not to apply external force, stress, and excessive vibration to the LED and follow the conditions below.

Baking temperature: 120°C max. Baking time: Within 60 seconds.

If soldering is done sequentially after the adhesive baking, please perform the soldering after cooling down the LED to normal temperature.

VER.: 01 Date: 2013/02/27 Page: 5/5